

### **Features**

- Super High Dense Cell Design
- Reliable and Rugged
- Lead Free Available (RoHS Compliant)

## **Applications**

- Portable Equipment and Battery Powered Systems
- DC-DC converter
- Load Switch

### **Product Summary**

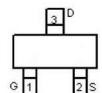


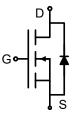
<b>V</b> DS	20	V
R DS(on),Typ@ VGS=4.5 V	11.5	mΩ
I D	12	Α

#### Top view









# **Absolute Maximum Ratings** ( $T_A=25$ °C Unless Otherwise Noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Drain Current - Continuous	I <sub>D</sub> (Ta=25℃)	12	А
Drain Current - Continuous	I <sub>D</sub> (Ta=70℃)	4.8	А
Drain Current – Pulsed	I <sub>DM</sub>	48	A
Gate-Source Voltage	$V_{GS}$	±8.0	V
Maximum Power Dissipation	P <sub>D</sub> (Ta=25℃)	1.14	W
Thermal Resistance Junction-to-Ambient	R <sub>θJA</sub>	110	°C/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ 150	°C



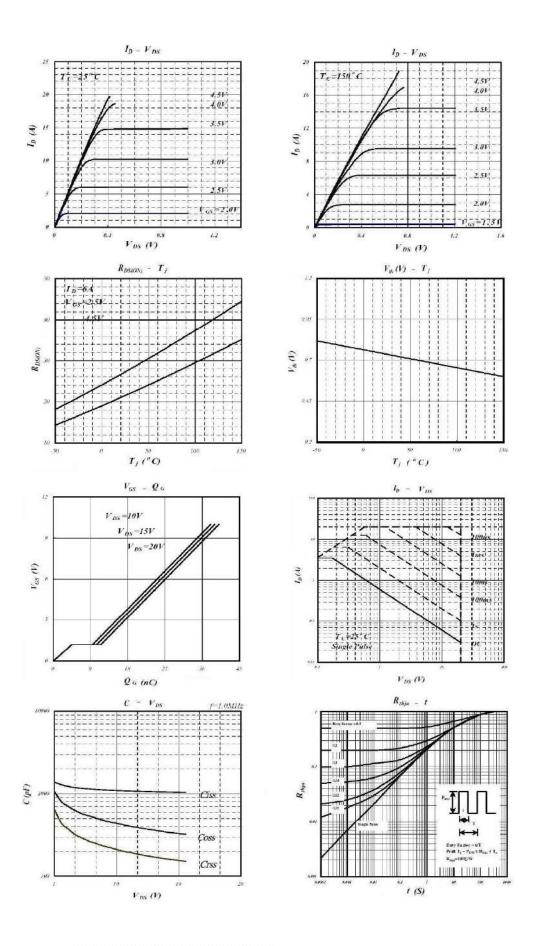
### **Electrical Characteristics** (T<sub>A</sub>=25°C Unless Otherwise Noted)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V	$I_D=250\mu A$	20			\
Drain-Source Leakage Current(T=25℃)	I <sub>DSS</sub>	V <sub>DS</sub> =16V	V <sub>GS</sub> =0V			1	μΑ
Drain-Source Leakage Current(T=70℃)	I <sub>DSS</sub>	V <sub>DS</sub> =16V	V <sub>GS</sub> =0V			30	μΑ
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 8V$	V <sub>DS</sub> =0V			±100	nA
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{DS}=V_{GS}$	I <sub>D</sub> =250μA	0.55		0.95	V
Static Drain-Source On-Resistance	D	V <sub>GS</sub> =4.5V	I <sub>D</sub> = 5 A		11.5	12	mΩ
	$R_{DS(on)}$	V <sub>GS</sub> =2.5V	I <sub>D</sub> = 3 A		19.5	20	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V	I <sub>D</sub> =6.0A		20		S
Forward On Voltage	$V_{\text{SD}}$	V <sub>GS</sub> =0V	I <sub>S</sub> =1.7A			1.3	V
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =20V V <sub>GS</sub> =0V f=1.0MHz			602		pF
Output Capacitance	C <sub>oss</sub>				186		pF
Reverse Transfer Capacitance	C <sub>rss</sub>				87		pF
Turn-on Delay Time	t <sub>d(on)</sub>	$V_{DS}$ =10V $I_{D}$ =1A $V_{GS}$ =5V $R_{G}$ =6 $\Omega$ $R_{D}$ =10 $\Omega$			30		ns
Rise Time	t <sub>r</sub>				70		ns
Turn-off Delay Time	t <sub>d(off)</sub>				40		ns
Fall Time	t <sub>f</sub>				65		ns

#### Notes:

- 1、Surface Mounted on FR4 Board, t ≤ 10 sec.
- 2、Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤2%.







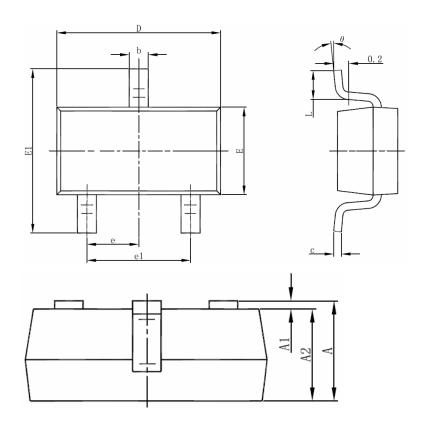
# **Ordering and Marking Information**

Ordering Device No.	Marking	Package	Packing	Quantity
ASDM20N12ZB-R	20N12	SOT23-3	Tape&Reel	3000/Reel

PACKAGE	MARKING
SOT23-3	Lot Number 20N12  Date Code



# **SOT-23-3L PACKAGE INFORMATION**



Cl	Dimensions Ir	n Millimeters	Dimensions	In Inches		
Symbol	Min	Max	Min	Max		
Α	1.050	1.250	0.041	0.049		
A1	0.000	0.100	0.000	0.004		
A2	1.050	1.150	0.041	0.045		
b	0.300	0.500	0.012	0.020		
С	0.100	0.200	0.004	0.008		
D	2.820	3.020	0.111	0.119		
Е	1.500	1.700	0.059	0.067		
E1	2.650	2.950	0.104	0.116		
е	0.950(BSC)		0.037(	37(BSC)		
e1	1.800	2.000	0.071	0.079		
L	0.300	0.600	0.012	0.024		
θ	0°	8°	0°	8°		



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